## NSN 5962-01-358-1170

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View Online at https://aerobasegroup.com/nsn/5962-01-358-1170						
Body Length:						
1.280 inches						
Body Width:						
Between 0.220 inches and 0.310 inches						
Body Height:						
Between 0.140 inches and 0.185 inches						
Maximum Power Dissipation Rating:						
1.0 watts						
Operating Tempurature Range:						
-55.0/+125.0 degrees celsius						
Storage Tempurature Range:						
-65.0/+150.0 degrees celsius						
Features Provided:						
Monolithic and w/clock						
Inclosure Material:						
Ceramic						
Inclosure Configuration:						
Dual-in-line						
Output Logic Form:						
Complementary-metal oxide-semiconductor logic						
Input Circuit Pattern:						
13 input						
Case Outline Source And Designator:						
D-9 mil-m-38510						
Current Rating Per Characteristic:						
120.00 milliamperes reverse current, dc absolute						
Terminal Surface Treatment:						
Solder						
Product Name:						
Registered prom						
Voltage Rating And Type Per Characteristic:						
-0.5 volts power source and 7.0 volts power source						
Capitance Rating Per Characteristic:						
6.00 input picofarads and 8.00 output picofarads						
Memory Device Type:						
Prom						
Test Data Document:						
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).						
Terminal Type And Quantity:						
24 printed circuit						
Shelf Life:						

N/a

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In	18	<i>(</i> )+	МЛО	201	ure:

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Demilitarization:

No

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